

IPP070N06N G

Request a Quote

IPP070N06N G Information

	Part Number	IPP070N06N G	
	Manufacturer	Infineon Technologies	
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 60V 80A TO-220	
12	Package	TO-220-3	
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP070N06N G Specifications

Manufacturer Part Number	IPP070N06N G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 180µA
Gate Charge (Qg) (Max) @ Vgs	118nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4100pF @ 30V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	250W (Tc)
Rds On (Max) @ Id, Vgs	7 mOhm @ 80A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

IPP070N06N G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP070N06N G Payment Methods



IPP070N06N G Shipping Methods



If you have any question about IPP070N06N G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com